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PTO/SB/08A (08-00)
Approved for use through 10/31/2002. OMB 0651-0031
U.S. Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE

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Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i>			Complete if Known		
			Application Number		
			Filing Date		
			First Named Inventor		
			Group Art Unit		
			Examiner Name		
			Attorney Docket Number		
Sheet	1	of	3		

U.S. PATENT DOCUMENTS						
Examiner Initials*	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code ² (if known)			
AL	A1	4,963,506		Liaw et al.	10-16-1990	
	A2	5,751,637		Chen et al.	05-12-1998	
	A3	5,753,134		Biebl	05/19/1998	
	A4	5,874,129		Beinglass et al.	02-23-1999	
	A5	6,268,068		Heuer et al.	07-31-2001	
AL	A6	6,373,092		Okumoto	04-16-2002	
	A7	10/180,168		Luoh	06-26-2002	(filing date)
	A8					
	A9					
	A10					
	A11					
	A12					
	A13					
	A14					
	A15					
	A16					
	A17					
	A18					
	A19					
	A20					

FOREIGN PATENT DOCUMENTS							
Examiner Initials*	Cite No. ¹	Foreign Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	Ts
		Office ³	Number ⁴				
	B1						
	B2						
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	B5						
	B6						
	B7						
	B8						
	B9						
	B10						

Examiner Signature		Date Considered	09/22/04
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¹ Unique citation designation number. ² See attached Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

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Substitute for form 1449B/PTO		Compleat If Known	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)		Application Number	
		Filing Date	16 July 2003 (herewith)
		First Named Inventor	Chih Yuan Huang et al.
		Group Art Unit	
		Examiner Name	
Sheet	2	of	3
		Attorney Docket Number	MXIC 1532-1

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS			
Examiner Initials	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
ah	C1	KAHLER, U., et al. "Size related properties of silicon nanoparticles from decomposition of SiOx" http://www.mpi-halle.mpg.de/annual_reports/2000.pdf/jb_results_14.pdf , 2 pages.	/
	C2	"Polysilicon: The Successor Technology," http://www.wtec.org/loyola/dsply_jp/c5_s5.htm (June 1992), 3 pages	/
	C3	Polysilicon TFT, The Future is clear with Toshiba, http://www.toshiba-europe.com/computers/tnt/tft/ (2002), 1 page	/
	C4	Higher Resolution, The Future is clear with Toshiba, http://www.toshiba-europe.com/computers/tnt/tft/resolution.htm (2002), 1 page	/
	C5	Polysilicon Explained, The future is clear with Toshiba, http://www.toshiba-europe.com/computers/tnt/tft/explained.htm (2002), 1 pate	/
	C6	"Flash Memory Technology" Chapter 10, Integrated Circuit Engineering Corporation, http://smithsonianchips.si.edu/ice/cd/MEMORY97/SEC10.PDF (1997), pp. 10-1 through 10-16.	/
	C7	WILSON, RON, "Flash gets a quantum makeover at IEDM," EETIMES (12/13/2002), 4 pages.	/
	C8	"The K-Input Floating-Gate MOS (FGMOS) Transistor" http://people.ece.cornell.edu/minch/talks/FGMOSTdevicelayout.pdf , 22 pages	/
	C9	DIPERT, BRIAN, "Exotic Memories, diverse approaches" www.ednmag.com (04/26/2001), 9 pages	/
	C10	LAMMERS, DAVID, "Chip makers bang away at metal gates" EETIMES (11/26/2002), 3 pages	/
ah	C11	"Characterizing Very Thin ONO Gates with Laser Spectroscopic Ellipsometry" Rudolph Technologies, Inc. Application Reports (2001) http://www.rudolphtech.com/reports/VeryThinONOGates.htm , 3 pages	/

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				First Named Inventor	Chih Yuan Huang et al.
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Sheet	3	of	3		

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Andy Kuykendall

09/22/02

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